

L Number	Hits	Search Text	DB	Time stamp
-	45	"5640343" and electrode	USPAT; US-PGPUB;	2002/11/04 11:17
	116	"5640343"	EPO; JPO; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 15:10
-	8	"5640343" and polymer	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 13:53
-	4	("5640343" and electrode) and polyme\$3	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 13:53
-	4	("5640343" and polymer) not (("5640343" and electrode) and polyme\$3)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:30
-	0	20020075719.URPN.	IBM_TDB USPAT	2002/11/04
_	0	(discrete adj polymer adj memory).ti.	USPAT; US-PGPUB; EPO; JPO; IBM TDB	13:58 2002/11/04 14:00
-	0	discrete adj polymer adj memory.ti.	USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:00
-	5	polymer adj memory.ti.	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:00
-	1	1166390.URPN.	IBM_TDB USPAT	2002/11/04
-	32	li-jian.in.	USPAT; US-PGPUB; EPO; JPO;	14:01 2002/11/04 14:34
-	3	li-jian.in. and electrode	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:34
-	0	mu-xiaochun	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:34
-	0	mu-xiaochun.in.	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:34
-	18	mu-xiao-chun.in.	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:38
-	12	(polymer adj memory) and electrode	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/04 14:45
-	0	20020105080.URPN.	IBM_TDB USPAT	2002/11/04
-	561	(polymer with memory) and electrode	USPAT; US-PGPUB; EPO; JPO;	14:44 2002/11/04 14:45
-	549	((polymer with memory) and electrode) not ((polymer adj memory) and electrode)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 14:45

-	358		USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	15:03
		and substrate	EPO; JPO;	
			IBM_TDB	
-	20		USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	14:47
		and substrate) and (polymer adj	EPO; JPO;	
		structure)	IBM_TDB	
-	1387	(((((polymer with memory) and electrode)	USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	14:48
		and substrate) and (polymer adj	EPO; JPO;	
1		structure)) ont mu-xiao-chun.in.	IBM TDB	
_	20	(((((polymer with memory) and electrode)	USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	14:48
		and substrate) and (polymer adj	EPO; JPO;	
		structure)) not mu-xiao-chun.in.	IBM TDB	
l <u>-</u>	7		USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	14:54
		and substrate) and (polymer adj	EPO; JPO;	* * * *
		structure)) not mu-xiao-chun.in.) and	IBM TDB	
	1	series	1211_122	
1_	13		USPAT;	2002/11/04
-	13		US-PGPUB;	14:54
		not ((polymer adj memory) and electrode))		1 7 2 1 2 2
1		and substrate) and (polymer adj	EPO; JPO;	
	1	structure)) not ((((((polymer with	IBM_TDB	
		memory) and electrode) not ((polymer adj		1
		memory) and electrode)) and substrate)		
		and (polymer adj structure)) not		
		mu-xiao-chun.in.) and series)		0000/11/01
-	72	1 1 1 1 1 2 1 2 1 1 1 1 1 1 1 1 1 1 1 1	USPAT;	2002/11/04
	1	not ((polymer adj memory) and electrode))	US-PGPUB;	15:04
	1	and substrate) and (first adj3 electrode)	EPO; JPO;	
	1		IBM_TDB	
-	0	(((((polymer with memory) and electrode)	USPAT;	2002/11/04
	1	not ((polymer adj memory) and electrode))	US-PGPUB;	15:05
		and substrate) and (first adj3	EPO; JPO;	ļ
		electrode)) and damascene	IBM TDB	
_	3963	1 1	USPĀT;	2002/11/04
			US-PGPUB;	15:05
	1		EPO; JPO;	
			IBM TDB	
_	30	(((((polymer with memory) and electrode)	USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	15:06
		and substrate) and (first adj3	EPO; JPO;	
		electrode)) and ferroelectric	IBM TDB	
1_	3	1 1	USPAT;	2002/11/04
		not ((polymer adj memory) and electrode))	US-PGPUB;	15:06
		and substrate) and (first adj3	EPO; JPO;	-0.00
		and substrate; and (lifst adjs electrode); and ferroelectric; and		
			IBM_TDB	
	1.3	protective	וופטאייי.	2002/11/04
_	13		USPAT;	15:06
		not ((polymer adj memory) and electrode))	US-PGPUB;	12:00
	1	and substrate) and (first adj3	EPO; JPO;	
	}	electrode)) and ferroelectric) and	IBM_TDB	
		protect\$4		2000/11/04
-	45	"5640343" and electrode	USPAT;	2002/11/04
			US-PGPUB;	15:10
			EPO; JPO;	1
	}		IBM_TDB	
-	43	("5640343" and electrode) and substrate	USPAT;	2002/11/04
			US-PGPUB;	15:10
			EPO; JPO;	
			IBM_TDB	
_	4	(("5640343" and electrode) and substrate)	USPĀT;	2002/11/04
	1	and polym\$3	US-PGPUB;	15:36
			EPO; JPO;	1
			IBM TDB	1
_	11	("5541868" "5640343" "5695864"	USPAT	2002/11/04
	**	"5734605" "5764567" "5793697"		17:01
		"5801984" "5841692" "6072718"		
		"6114719" "6130835").PN.		
L	L	1 0111111 010000 /.14.	L	<u> </u>

-	4	("3623038" "5055158" "5390061" "5432734").PN.	USPAT	2002/11/04 15:17
_	11	("2683856" "3813692" "4103315" "4825325" "4894741" "4896235" "4940511" "5014147" "5134533"	USPAT	2002/11/04 15:22
		"5159513" "5206590").PN.		
-	54	5390061.URPN.	USPAT	2002/11/04 15:24
_	1	"5390061".PN.	USPAT	2002/11/04 15:30
	113	(("5640343" and electrode) and substrate) or ((("5640343" and electrode) and substrate) and polym\$3) or (("5541868" "5640343" "5695864" "5734605" "5764567" "5793697" "5801984" "5841692" "6072718" "6114719" "6130835").PN.) or (("3623038" "5055158" "5390061" "5432734").PN.) or (("2683856" "3813692" "4103315" "4825325" "4894741" "4896235" "4940511" "5014147" "5134533" "5159513" "5206590").PN.) or 5390061.URPN. or "5390061".PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/11/04 15:37
	6		USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/11/04
-	6	("5640343" "5734605" "6097625" "6180444" "6190998" "6242770").PN.	USPAT	2002/11/04 17:09
_	790	substrate and (ferroelectric with polym\$4) and electrode	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 17:13
-	117	(substrate and (ferroelectric with polym\$4) and electrode) and (first adjelectrode)	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:01
-	46	((substrate and (ferroelectric with polym\$4) and electrode) and (first adjelectrode)) and memory	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 17:14
_	0	(((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and memory) and damascene	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 17:16
_	15	<pre>(((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and memory) and (ferroelectric adj3 polym\$3)</pre>	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:02
-	3	<pre>((((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and memory) and (ferroelectric adj3 polym\$3)) and (logic adj element)</pre>	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/11/04 17:20
-	31	(((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and memory) not ((((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and memory) and (ferroelectric adj3 polym\$3))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/11/04 17:48

			_	
_	4	(substrate and (ferroelectric with polym\$4) and electrode) and (memory adj	USPAT; US-PGPUB;	2002/11/04 17:54
_	88	((substrate and (ferroelectric with	EPO; JPO; IBM_TDB USPAT;	2002/11/04
		polym\$4) and electrode) and (first adj electrode)) and (cross)	US-PGPUB; EPO; JPO;	18:01
-	99	((substrate and (ferroelectric with polym\$4) and electrode) and (first adj	IBM_TDB USPAT; US-PGPUB;	2002/11/04 18:01
		electrode)) and (cross or perpendicular)	EPO; JPO; IBM_TDB	
	51	<pre>(((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and (cross or perpendicular))</pre>	USPAT; US-PGPUB; EPO; JPO;	2002/11/04
-	38	and (ferroelectric adj3 polym\$3) ((((substrate and (ferroelectric with polym\$4) and electrode) and (first adj	IBM_TDB USPAT; US-PGPUB;	2002/11/04
		electrode)) and (cross or perpendicular)) and (ferroelectric adj3 polym\$3)) not (((substrate and (ferroelectric with polym\$4) and electrode) and (first adj electrode)) and memory)	EPO; JPO; IBM_TDB	
-	1362	polym\$4 with ferroelectric	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:31
-	284	<pre>(polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))</pre>	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:32
-	284	((polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))) and (ferroelectric adj\$3 polymer)	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:34
_	284	((polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))) and (ferroelectric adj\$ polymer)	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:36
-	53	<pre>((polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))) and (ferroelectric adj polymer)</pre>	USPĀT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:36
-	49	<pre>(((polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))) and (ferroelectric adj polymer)) and substrate</pre>	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/04 18:36
-	33	<pre>((((polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))) and (ferroelectric adj polymer)) and substrate) and (protect\$4 or cover or package)</pre>	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/11/04 18:38
-	1		USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2002/11/04 18:39
_	0	20020105080.URPN.	USPAT	2002/11/04 18:43
-	0	20020105080.URPN.	USPAT	2002/11/04 18:43
-	1	(US-20020105080-\$).did.	US-PGPUB	2002/11/05 10:00
_	24	<pre>((((((polym\$4 with ferroelectric) and (memory and (cross or perpendicula\$3))) and (ferroelectric adj polymer)) and substrate) and (protect\$4 or cover or</pre>	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/05
		package)) and electrode) and organic		

-	0	polymer adj memory adj device.ti.	USPAT; US-PGPUB;	2002/11/05 10:02
-	3	polymer adj memory adj device	EPO; JPO; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/05 10:10
_	2	("5363329" "5920788").PN.	IBM_TDB USPAT	2002/11/05
_	0	6072716.URPN.	USPAT	10:09
_	0	6072716.URPN.	USPAT	10:09
_	13		USPAT;	10:09 2002/11/05
		ferroelectric)	US-PGPUB; EPO; JPO;	10:11
-	0	(memory and (ferroelectric near3 polym))	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/05
	230	(memory and (ferroelectric near3 polym\$3))	IBM_TDB USPAT; US-PGPUB;	2002/11/05 10:15
-	180	((memory and (ferroelectric near3 polym\$3))) and substrate	EPO; JPO; IBM_TDB USPAT; US-PGPUB;	2002/11/05 10:15
_	127	<pre>(((memory and (ferroelectric near3 polym\$3))) and substrate) and (cross or</pre>	EPO; JPO; IBM_TDB USPAT; US-PGPUB;	2002/11/05 10:15
-	81	perpendicular) ((((memory and (ferroelectric near3	EPO; JPO; IBM_TDB USPAT;	2002/11/05
		polym\$3))) and substrate) and (cross or perpendicular)) and organic	US-PGPUB; EPO; JPO; IBM_TDB	10:16
_	55	<pre>(((((memory and (ferroelectric near3 polym\$3))) and substrate) and (cross or perpendicular)) and organic) and (cover or protect\$3 or package)</pre>	USPAT; US-PGPUB; EPO; JPO; IBM TDB	2002/11/05
-	48	<pre>((((((memory and (ferroelectric near3 polym\$3))) and substrate) and (cross or perpendicular)) and organic) and (cover</pre>	USPĀT; US-PGPUB; EPO; JPO;	2002/11/05
-	0	or protect\$3 or package)) and electrode (((((((memory and (ferroelectric near3 polym\$3))) and substrate) and (cross or perpendicular)) and organic) and (cover	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/11/05 10:17
	7	or protect\$3 or package)) and electrode) and damascene (((((((memory and (ferroelectric near3	IBM_TDB USPAT;	2002/11/05
		<pre>polym\$3))) and substrate) and (cross or perpendicular)) and organic) and (cover or protect\$3 or package)) and electrode) and (second adj electrode)</pre>	US-PGPUB; EPO; JPO; IBM_TDB	10:27
-	41	<pre>(((((((memory and (ferroelectric near3 polym\$3))) and substrate) and (cross or perpendicular)) and organic) and (cover</pre>	USPAT; US-PGPUB; EPO; JPO;	2002/11/05 10:28
		or protect\$3 or package)) and electrode) not (((((((memory and (ferroelectric near3 polym\$3))) and substrate) and (cross or perpendicular)) and organic) and (cover or protect\$3 or package)) and	IBM_TDB	
-	12	electrode) and (second adj electrode)) ("4748464" "4833990" "4872962" "4959668" "5191834" "5194881" "5211113" "5402158" "5454318"	USPAT	2002/11/05
		"5555809" "5640189" "5786048").PN.	<u></u>	L

-	15	1 (12 12 12 1 2 2 2 2 2 2 2 2 2 2 2 2 2	USPAT;	2003/02/24
		US-6269018-\$ or US-6072716-\$ or	US-PGPUB	12:31
		US-4873455-\$ or US-6072718-\$ or		
		US-5841692-\$ or US-5390061-\$ or		
		US-5432734-\$ or US-3623038-\$ or		
		US-6077618-\$ or US-5146299-\$ or		
	1	US-5927206-\$).did. or (US-20020081753-\$		İ
	1	or US-20020075719-\$).did.		
-	14	,, , , , ,	USPAT;	2003/02/24
	İ	US-6269018-\$ or US-6072716-\$ or	US-PGPUB;	12:32
		US-4873455-\$ or US-6072718-\$ or	EPO; JPO;	1
		US-5841692-\$ or US-5390061-\$ or	IBM_TDB	
	į.	US-5432734-\$ or US-3623038-\$ or	ļ	Į į
		US-6077618-\$ or US-5146299-\$ or		
		US-5927206-\$).did. or (US-20020081753-\$	1	i
		or US-20020075719-\$).did.) and (pattern\$4	İ	!
	0	or etch\$4 or remov\$3) 20020075719.URPN.	Man n	0000 (00 (04
1		20020073719.0RPN.	USPAT	2003/02/24
	0	2002007F710 IMPDN	TIGE TO	12:47
_	1	20020075719.URPN.	USPAT	2003/02/24
_	833	(memory adj array) and ferroelectric	USPAT;	12:47 2003/02/24
ļ	022	(memory adj array) and refroefection	US-PGPUB;	17:45
			EPO; JPO;	1,,42
			IBM TDB	
_	447	((memory adj array) and ferroelectric)	USPAT;	2003/02/24
	1	and (bit adj line) and (word adj line)	US-PGPUB;	17:46
		and (bis adj line) and (word adj line)	EPO; JPO;	17.30
			IBM TDB	İ
_	64	(((memory adj array) and ferroelectric)	USPAT;	2003/02/24
		and (bit adj line) and (word adj line))	US-PGPUB;	18:21
		and ((bit adj line) and (word adj line))	EPO; JPO;	1 20.22
		with cross	IBM TDB	
-	61	((((memory adj array) and ferroelectric)	USPĀT;	2003/02/24
		and (bit adj line) and (word adj line))	US-PGPUB;	17:47
	1	and ((bit adj line) and (word adj line))	EPO; JPO;	-
		with cross) and (method or process)	IBM TDB	
-	48	(((((memory adj array) and ferroelectric)	USPAT;	2003/02/24
		and (bit adj line) and (word adj line))	US-PGPUB;	17:48
		and ((bit adj line) and (word adj line))	EPO; JPO;	1
		with cross) and (method or process)) and	IBM_TDB	
1	1	(etch\$4 or remov\$4 or pattern\$4)		
-	29	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	USPAT;	2003/02/24
1	1	ferroelectric) and (bit adj line) and	US-PGPUB;	18:03
1		(word adj line)) and ((bit adj line) and	EPO; JPO;	
İ	l .	(word adj line)) with cross) and (method	IBM_TDB	
	!	or process)) and (etch\$4 or remov\$4 or		
	1	<pre>pattern\$4)) and (electrode)</pre>		0000/00/00
1 -	19	[(((((((((((((((((((USPAT;	2003/02/24
	1	ferroelectric) and (bit adj line) and	US-PGPUB;	18:20
]		(word adj line)) and ((bit adj line) and	EPO; JPO;	
		(word adj line)) with cross) and (method	IBM_TDB	
		or process)) and (etch\$4 or remov\$4 or]
]		pattern\$4)) not ((((((memory adj array)		
		and ferroelectric) and (bit adj line) and		
	ļ	(word adj line)) and ((bit adj line) and (word adj line)) with cross) and (method		
		or process)) and (etch\$4 or remov\$4 or		
		pattern\$4)) and (electrode))		
	765	tunnel adj junction and memory	USPAT;	2003/02/24
'	'65	conner adj junction and memory	USPAT; US-PGPUB;	18:21
]		EPO; JPO;	10.21
			IBM TDB	i
_	51	(tunnel adj junction and memory) and	USPAT;	2003/02/24
		((bit adj line) and (word adj line)) with	US-PGPUB;	18:22
		cross	EPO; JPO;	
			IBM TDB	
L	L	<u> </u>		L

-	49	((tunnel adj junction and memory) and	USPAT;	2003/02/25
		((bit adj line) and (word adj line)) with	US-PGPUB;	11:23
		cross) not (((((memory adj array) and	EPO; JPO;	
		ferroelectric) and (bit adj line) and	IBM_TDB	
		(word adj line)) and ((bit adj line) and		
		(word adj line)) with cross) and (method	ļ	
		or process))		
_	0	20020122338.URPN.	USPAT	2003/02/24
	30	/!! 4700040!! !! 5507040!! !! 5640040!!	110000	18:38
-	30	("4780848" "5587943" "5640343" "5748524" "5793697" "5861328"	USPAT	2003/02/24
		3746324 3793697 3661326 "5956267" "5966323" "6005800"		18:40
		"6034887" "6081446" "6097625"		
	ļ	"6104633" "6134139" "6166948"		
		"6172904" "6174737" "6191972"		
		"6191973" "6211090" "6211559"		
		"6219212" "6219275" "6226160"		
		"6233172" "6242770" "6256223"		
		"6256247" "6259586" "6269018").PN.		i i
_	5	("5640343" "5650958" "5801984"	USPAT	2003/02/24
	1	"5841692" "5966012").PN.		18:41
_	16	("3037199" "4722073" "4860254"	USPAT	2003/02/24
		"4887236" "5025416" "5039655"		18:43
		"5055158" "5173873" "5276639"		
		"5329486" "5343422" "5347485"		
		"5361226" "5432734" "5448515"		
		"5449935").PN.		
-	3	("3341827" "3452333" "3541532").PN.	USPAT	2003/02/24
				18:45
-	16	("3037199" "4722073" "4860254"	USPAT	2003/02/24
		"4887236" "5025416" "5039655"		18:48
		"5055158" "5173873" "5276639"		
		"5329486" "5343422" "5347485"		
		"5361226" "5432734" "5448515"		
		"5449935").PN.		
-	8	(method or process) near3 (form\$4 adj	USPAT;	2003/02/25
		memory) and (tunnel adj junction)	US-PGPUB;	13:04
			EPO; JPO;	
			IBM_TDB	0000 (00 (05
~	0	20020093845.URPN.	USPAT	2003/02/25
		(#4500040# #5505042# #5640042#		11:31
-	30	("4780848" "5587943" "5640343"	USPAT	2003/02/25
		"5748524" "5793697" "5861328"		11:33
		"5956267" "5966323" "6005800"		
		"6034887" "6081446" "6097625" "6104633" "6134139" "6166948"		
1		"6172904" "6174737" "6191972" "6191973" "6211090" "6211559"		
		"6219212" "6219275" "6226160"		
		6219212	\ 	
		"6256247" "6259586" "6269018").PN.		
-	1	2001-004395	USPAT;	2003/02/25
		, 	US-PGPUB;	13:05
	1		EPO; JPO;	
			IBM TDB	
-	0	Jp2001-004395	USPĀT;	2003/02/25
1			US-PGPUB;	13:05
			EPO; JPO;	
			IBM TDB	
-	0	Jp004395	USPAT;	2003/02/25
1			US-PGPUB;	13:06
1	[EPO; JPO;	
			IBM_TDB	
-	0	Jp-004395	USPĀT;	2003/02/25
			US-PGPUB;	13:06
			EPO; JPO;	
		l	IBM_TDB	
-	1	(2001-004395).jp	USPAT;	2003/02/25
1			US-PGPUB;	13:08
1]		EPO; JPO;	
			IBM TDB	

	0	JP004395	TICDAM.	T 2002 (02 (25
		0 = 0 0 4 3 9 3	USPAT; US-PGPUB;	2003/02/25
				13:08
			EPO; JPO;	
_	0	JP-004395	IBM_TDB	2002/02/25
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_	28	mu-xiao-chun.in.	USPAT;	2003/09/04
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		(ferroelectric)	EPO; JPO;	
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